

Photocouplers GaAlAs Infrared LED & Photo IC

TLP152

1. Applications

- · Plasma Display Panels (PDPs)
- · Industrial Inverters
- · MOSFET Gate Drivers
- · IGBT Gate Drivers

2. General

The TLP152 is a photocoupler in an SO6 package that consists of a GaAlAs infrared light-emitting diode (LED) optically coupled to an integrated high-gain, high-speed photodetector IC chip. The photodetector IC chip has an internal shield to provide a high common-mode transient immunity of $\pm 20\,\mathrm{kV/\mu s}$ and thus superior noise immunity between the input and output pins. The TLP152 has a totem-pole output that can both sink and source current. It is suitable for directly driving a small IGBT or power MOSFET.

3. Features

- (1) Buffer logic type (totem pole output)
- (2) Output peak current: ±2.5 A (max)
- (3) Operating temperature: -40 to 100 °C
- (4) Supply current: 3.0 mA (max)
- (5) Supply voltage: 10 to 30 V
- (6) Threshold input current: 7.5 mA (max)
- (7) Propagation delay time: $t_{pHL} = 190 \text{ ns (max)}$, $t_{pLH} = 170 \text{ ns (max)}$
- (8) Common-mode transient immunity: ±20 kV/µs (min)
- (9) Isolation voltage: 3750 Vrms (min)
- (10) Safety standards

UL-approved: UL1577, File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN60747-5-5, EN60065 or EN60950-1 (Note 1)

CQC-approved: GB4943.1, GB8898 Thailand Factory

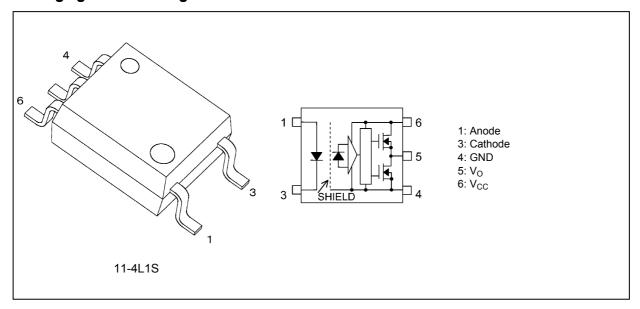


仅适用干海拔 2000m 以下地区安全使用

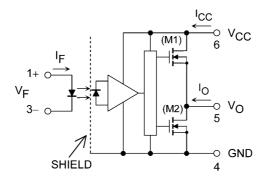
Note 1: When a VDE approved type is needed, please designate the Option (V4).



4. Packaging and Pin Assignment



5. Internal Circuit (Note)



Note: A 0.1- μF bypass capacitor must be connected between pin 6 and pin 4.

6. Principle of Operation

6.1. Truth Table

Input	LED	M1	M2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	Ĺ

6.2. Mechanical Parameters

Characteristics	Size	Unit
Creepage distances	5.0 (min)	mm
Clearance distances	5.0 (min)	
Internal isolation thickness	0.4 (min)	

Rev.5.0



7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		20	mA
	Peak transient input forward current		I _{FPT}	(Note 1)	1	А
	Input reverse voltage		V _R		5	V
	Input power dissipation		P _D		40	mW
Detector	Peak high-level output current	$(T_a = -40 \text{ to } 100 ^{\circ}\text{C})$	I _{OPH}	(Note 2)	-2.5	Α
	Peak low-level output current	$(T_a = -40 \text{ to } 100 ^{\circ}\text{C})$	I _{OPL}	(Note 2)	+2.5	
	Output voltage		Vo		35	V
	Supply voltage		V _{CC}		35	
	Output power dissipation		Po		260	mW
	Output power dissipation derating	(T _a ≥ 85 °C)	$\Delta P_{O}/\Delta T_{a}$		-2.0	mW/°C
Common	Operating temperature		T _{opr}		-40 to 100	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}	(Note 3)	260	
	Isolation voltage	(AC, 60 s, R.H. ≤ 60 %)	BV _S	(Note 4)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width (PW) \leq 1 μ s, 300 pps
- Note 2: Exponential waveform. Pulse width $\leq 0.2~\mu s$, f $\leq 15~kHz$, V_{CC} = 20 V, T_a = -40 to 100 °C Exponential waveform. Pulse width $\leq 0.08~\mu s$, f $\leq 25~kHz$, V_{CC} = 15 V, T_a = -40 to 100 °C
- Note $3: \ge 2$ mm below seating plane.
- Note 4: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I _{F(ON)}	(Note 1)	10		15	mA
Input off-state voltage	V _{F(OFF)}		0		0.8	V
Peak high-level output current	I _{OPH}		_	_	-2.0	Α
Peak low-level output current	I _{OPL}		_	_	+2.0	
Operating frequency	f	(Note 2)	1	_	250	kHz

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a high-gain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

- Note 1: The rise and fall times of the input on-current should be less than 0.5 μ s.
- Note 2: Exponential waveform. $I_{OPH} \ge -0.65 \text{ A} \ (\le 80 \text{ ns}), \ I_{OPL} \le 0.65 \text{ A} \ (\le 80 \text{ ns}), \ T_a = 100 \,^{\circ}\text{C}, \ V_{CC} = 20 \,^{\circ}\text{V}$



9. Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 100 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F		_	I _F = 10 mA, T _a = 25 °C	1.40	1.57	1.80	V
Input forward voltage temperature coefficient	$\Delta V_F/\Delta T_a$		_	I _F = 10 mA	_	-1.8		mV/°C
Input reverse current	I _R		_	V _R = 5 V, T _a = 25 °C	_		10	μА
Input capacitance	Ct		_	V = 0 V, f = 1 MHz, T _a = 25 °C	_	45	_	pF
Peak high-level output current	I _{OPH}	(Note 1)	Fig. 12.1.1	I _F = 10 mA, V _{CC} = 15 V, V ₆₋₅ = 4 V	_	-2.2	-1.0	Α
				I _F = 10 mA, V _{CC} = 15 V, V ₆₋₅ = 10 V	_	-3.4	-2.0	
Peak low-level output current	I _{OPL}	(Note 1)	Fig. 12.1.2	I _F = 0 mA, V _{CC} = 15 V, V ₅₋₄ = 2 V	1.0	2.4	_	
				I _F = 0 mA, V _{CC} = 15 V, V ₅₋₄ = 10 V	2.0	3.5	_	
High-level output voltage	V _{OH}		Fig. 12.1.3	I _F = 10 mA, V _{CC} = 10 V, I _O = -100 mA	6.0	8.5	ı	V
Low-level output voltage	V _{OL}		Fig. 12.1.4	V _F = 0.8 V, V _{CC} = 10 V, I _O = 100 mA	_	0.1	1.0	
High-level supply current	I _{CCH}		Fig. 12.1.5	$I_F = 10 \text{ mA}, V_{CC} = 10 \text{ to } 30 \text{ V}, V_O = \text{Open}$	_	1.9	3.0	mA
Low-level supply current	I _{CCL}		Fig. 12.1.6	$I_F = 0 \text{ mA}, V_{CC} = 10 \text{ to } 30 \text{ V}, V_O = \text{Open}$	_	1.8	3.0	
Threshold input current (L/H)	I _{FLH}		_	V _{CC} = 15 V, V _O > 1 V	_	1.5	7.5	
Threshold input voltage (H/L)	V _{FHL}		_	V _{CC} = 15 V, V _O < 1 V	0.8	1.47	_	V
Supply voltage	V _{CC}		_		10		30	
UVLO threshold voltage	V _{UVLO} +		_	I _F = 5 mA, V _O > 2.5 V	7.8	8.7	9.7	
	V _{UVLO} -			I _F = 5 mA, V _O < 2.5 V	7.5	8.4	9.4	
UVLO hysteresis	UVLO _{HYS}		_	I _F = 5 mA, V _O > 2.5 V	_	0.3	_	

Note: All typical values are at $T_a = 25$ °C.

Note: This device is designed for low power consumption, making it more sensitive to ESD than its predecessors.

Extra care should be taken in the design of circuitry and pc board implementation to avoid ESD problems.

Note 1: I_O application time $\leq 50~\mu s,$ single pulse.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Conditions	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.35	_	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. \leq 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	3750			Vrms
			AC, 1 s in oil	_	10000	_	
			DC, 60 s in oil		10000		Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



11. Switching Characteristics (Note) (Unless otherwise specified, T_a = -40 to 100 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (L/H)	t _{pLH}	(Note 1)	Fig. 12.1.7	$\begin{split} I_F &= 0 \rightarrow 10 \text{ mA, V}_{CC} = 30 \text{ V,} \\ R_g &= 20 \ \Omega, \ C_g = 10 \text{ nF,} \\ T_a &= 25 \ ^{\circ}\text{C} \end{split}$	60	95	145	ns
Propagation delay time (H/L)	t _{pHL}	(Note 1)		$\begin{split} I_F &= 10 \rightarrow 0 \text{ mA, V}_{CC} = 30 \text{ V,} \\ R_g &= 20 \ \Omega, \ C_g = 10 \text{ nF,} \\ T_a &= 25 \ ^{\circ}\text{C} \end{split}$	60	110	165	
Propagation delay time (L/H)	t _{pLH}	(Note 1)		$I_F = 0 \rightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 20 \Omega, C_g = 10 \text{ nF}$	50	95	170	
Propagation delay time (H/L)	t _{pHL}	(Note 1)		I_F = 10 \rightarrow 0 mA, V_{CC} = 30 V, R_g = 20 Ω , C_g = 10 nF	50	110	190	
Propagation delay skew (device to device)	t _{psk}	(Note 1) (Note 4)		$I_F = 0 \longleftrightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 20 \Omega, C_g = 10 \text{ nF}$	-85		85	
Pulse width distortion	t _{pHL} -t _{pLH}	(Note 1)		$I_F = 0 \longleftrightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 20 \Omega, C_g = 10 \text{ nF}$	l	15	50	
Rise time	t _r	(Note 1)		$I_F = 0 \rightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 20 \Omega, C_g = 10 \text{ nF}$		18		
Fall time	t _f	(Note 1)		$I_F = 10 \rightarrow 0$ mA, $V_{CC} = 30$ V, $R_g = 20 \Omega$, $C_g = 10$ nF	l	22	ı	
Common-mode transient immunity at output high	CM _H	(Note 2)	Fig. 12.1.8	$V_{CM} = 1000 V_{p-p}, I_F = 10 \text{ mA}, V_{CC} = 30 \text{ V}, T_a = 25^{\circ}\text{C}, V_{O(\text{min})} = 26 \text{ V}$	±20	I	I	kV/μs
Common-mode transient immunity at output low	CM _L	(Note 3)		V_{CM} = 1000 V_{p-p} , I_F = 0 mA, V_{CC} = 30 V, T_a = 25°C, $V_{O(max)}$ = 1 V	±20	_	_	

Note: All typical values are at $T_a = 25$ °C.

Note 1: Input signal (f = 125 kHz, duty = 50 %, $t_r = t_f = 5$ ns or less). CL is approximately 15 pF which includes probe and stray wiring capacitance.

- Note 2: CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 26 \text{ V}$).
- Note 3: CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state ($V_O < 1 V$).
- Note 4: The propagation delay skew, t_{psk}, is equal to the magnitude of the worst-case difference in t_{pHL} and/or t_{pLH} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).



12. Test Circuits and Characteristics Curves

12.1. Test Circuits

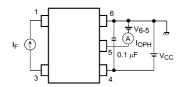


Fig. 12.1.1 IOPH Test Circuit

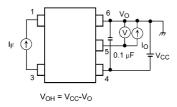


Fig. 12.1.3 V_{OH} Test Circuit

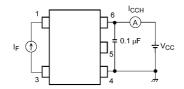


Fig. 12.1.5 I_{CCH} Test Circuit

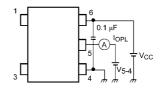


Fig. 12.1.2 I_{OPL} Test Circuit

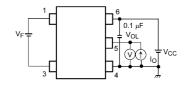


Fig. 12.1.4 V_{OL} Test Circuit

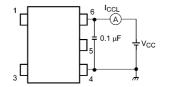


Fig. 12.1.6 I_{CCL} Test Circuit

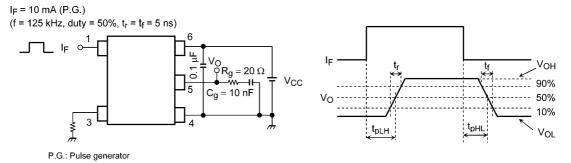


Fig. 12.1.7 Switching Time Test Circuit and Waveform

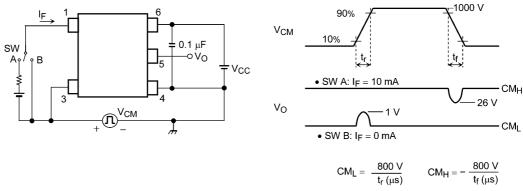


Fig. 12.1.8 Common-Mode Transient Immunity Test Circuit and Waveform



13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

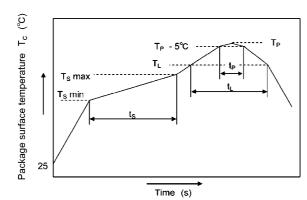
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	S
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	217		°C
Time above T _L	t∟	60	150	s
Peak temperature	T _P		260	°C
Time during which T_c is between $(T_P - 5)$ and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

Fig. 13.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

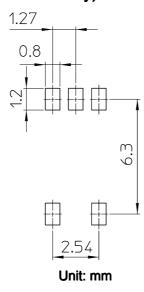
Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

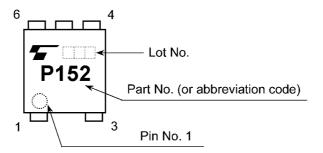
- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



14. Land Pattern Dimensions (for reference only)



15. Marking





16. Specifications for Embossed-Tape Packing

16.1. Applicable Package

Package Name	Product Type
SO6	Mini flat coupler

16.2. Product Naming Conventions

Type of package used for shipment is denoted by a symbol suffix after a part number. The method of classification is as below.

Example) TLP152(TPL,E(T

Part number: TLP152 Tape type: TPL

[[G]]/RoHS COMPATIBLE: E (Note 1)

Domestic ID (Country/Region of origin: Thailand): T

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

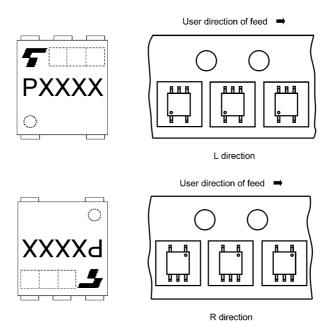
RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

16.3. Tape Dimensions Specification

Tape Type	Division	Packing Amount (A unit per reel)
TPL	L direction	3000
TPR	R direction	3000

16.3.1. Orientation of Device in Relation to Direction of Feed

Device orientation in the carrier cavities as shown in the following figure.



Device Orientation



16.3.2. Empty Cavities

Characteristics	Criterion	Remarks
Occurrences of 2 or more successive empty cavities	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty cavity	6 devices (max) per reel	Not including leader and trailer

16.3.3. Tape Leader and Trailer

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and a cover tape of 30 mm or longer.

16.3.4. Tape Dimensions

Tape material: Plastic (for protection against static electricity)

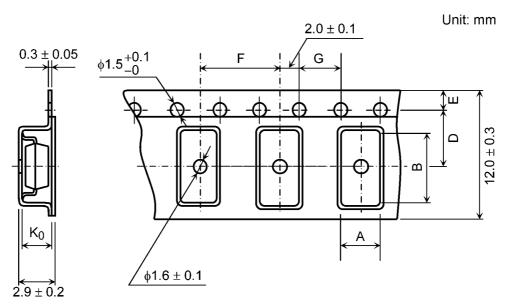


Table Tape Dimensions (unit: mm, tolerance: ±0.1)

Symbol	Dimension	Remark
Α	4.0	_
В	7.6	_
D	5.5	Center line of embossed cavity and sprocket hole
E	1.75	Distance between tape edge and sprocket hole center
F	8.0	Cumulative error +0.1/-0.3 (max) per 10 empty cavities holes
G	4.0	Cumulative error +0.1/-0.3 (max) per 10 sprocket holes
K ₀	2.6	Internal space

Rev.5.0



16.3.5. Reel Specification

Material: Plastic (for protection against static electricity)

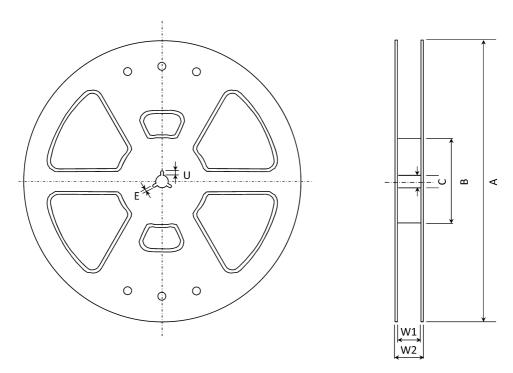
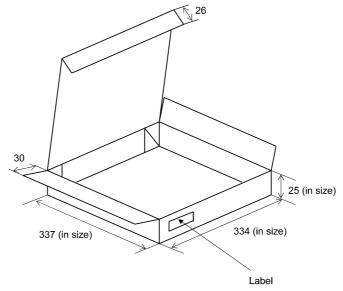


Table Reel Dimensions (unit: mm)

Symbol	Dimension
Α	$\phi 330 \pm 2.0$
В	ф80 ± 1.0
С	ф13 ± 0.5
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	13.5 ± 0.5
W2	17.5 ± 1.0



16.3.6. Packing (Note)



1 reel/carton (unit: mm)

Note: Taping reel diameter: \$\phi330 mm

16.3.7. Label Format

- (1) Carton: The label provides the part number, quantity, lot number, the Toshiba logo, etc.
- (2) Reel: The label provides the part number, the taping name, quantity, lot number, etc.

16.4. Ordering Information

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example) TLP152(TPL,E(T 3000 pcs

Part number: TLP152

Tape type: TPL (8-mm pitch)

[[G]]/RoHS COMPATIBLE: E (Note 1)

Domestic ID (Country/Region of origin: Thailand): T Quantity (must be a multiple of 3000): 3000 pcs

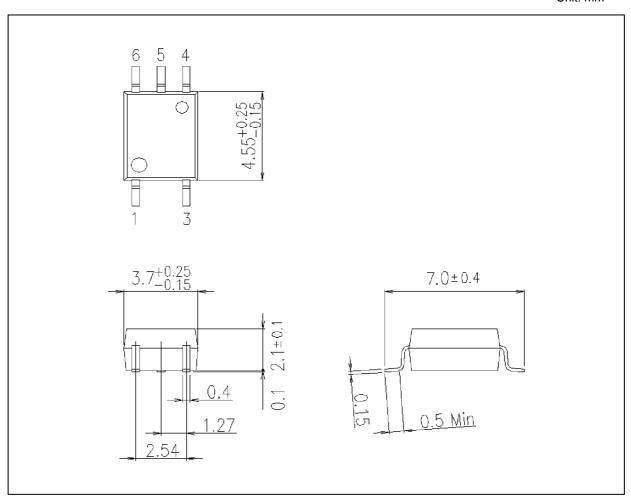
Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



Package Dimensions

Unit: mm



Weight: 0.08 g (typ.)

Package Name(s)	
TOSHIBA: 11-4L1S	

Rev.5.0



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